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September 2013

# FPF1320 / FPF1321

# IntelliMAX™ Dual-Input Single-Output Advanced Power Switch with True Reverse-Current Blocking

#### **Features**

- DISO Load Switches
- Input Supply Operating Range: 1.5 V ~ 5.5 V
- R<sub>ON</sub> 50 mΩ at V<sub>IN</sub>=3.3 V Per Channel (Typical)
- True Reverse-Current Blocking (TRCB)
- Fixed Slew Rate Controlled 130 µs for < 1 µF C<sub>OUT</sub>
- I<sub>SW</sub>: 1.5 A Per Channel (Maximum)
- Quick Discharge Feature on FPF1321
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
  - Human Body Model: >6 kV
  - Charged Device Model: >1.5 kV
  - IEC 61000-4-2 Air Discharge: >15 kV
  - IEC 61000-4-2 Contact Discharge: >8 kV

# **Applications**

- Smart phones / Tablet PCs
- Portable Devices
- Near Field Communication (NFC) Capable SIM Card Power Supply

# **Description**

The FPF1320/21 is a Dual-Input Single-Output (DISO) load switch consisting of two sets of slew-rate controlled, low on-resistance, P-channel MOSFET switches and integrated analog features. The slew-rate-controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on the power rails. The input voltage range operates from 1.5 V to 5.5 V to align with the requirements of low-voltage portable device power rails. FPF1320/21 performs seamless power-source transitions between two input power rails using the SEL pin with advanced break-before-make operation.

FPF1320/21 has a TRCB function to block unwanted reverse current from output to input during ON/OFF states. The switch is controlled by logic inputs of the SEL and EN pins, which are capable of interfacing directly with low-voltage control signals (GPIO).

FPF1321 has 65  $\Omega$  on-chip load resistor for output quick discharge when EN is LOW.

FPF1320/21 is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, with 0.5 mm pitch. FPF1321B is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, 0.5 mm pitch with backside laminate.

# **Ordering Information**

Part Number	Top Mark	Channel	Switch Per Channel (Typ.) at 3.3 V <sub>IN</sub>	Reverse Current Blocking	Output Discharge	Rise Time (t <sub>R</sub> )	Package	
FPF1320UCX	QS	DISO	50 mΩ	Yes	NA	130 µs	1.0 mm X 1.5 mm Wafer-Level Chip-	
FPF1321UCX	QT	DISO	50 mΩ	Yes	65 Ω	130 µs	Scale Package (WLCSP) 6-Bumps, 0.5 mm Pitch	
FPF1321BUCX	QT	DISO	50 mΩ	Yes	65 Ω	130 µs	1.0 mm X 1.5 mm Wafer-Level Chip- Scale Package (WLCSP) 6-Bumps, 0.5 mm Pitch with Backside Laminate	

# **Application Diagram**

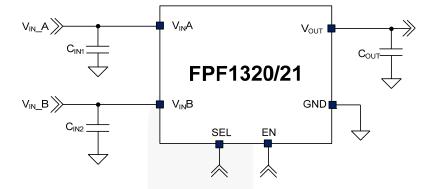


Figure 1. Typical Application

# **Block Diagram**

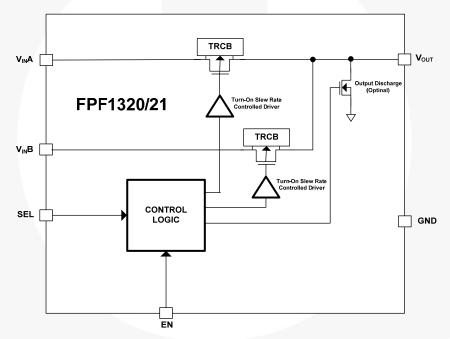
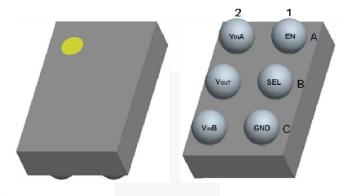


Figure 2. Functional Block Diagram (Output Discharge Path for FPF1321 Only)

# **Pin Configuration**

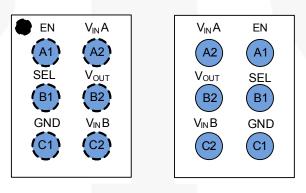


Pin Configuration in Package View with Pin 1 Indicator Figure 3.

**Bottom View** 

**Bottom View** 

Top View



Top View Figure 4. Pin Assignments

# **Pin Description**

Pin #	Name	Description
A1	EN	Enable input. Active HIGH. There is an internal pull-down resistor at the EN pin.
B1	SEL	Input power selection inputs. See Table 1. There are internal pull-down resistors at the SEL pins.
A2	V <sub>IN</sub> A	Supply Input. Input to the power switch A.
B2	$V_{OUT}$	Switch output
C1	GND	Ground
C2	V <sub>IN</sub> B	Supply Input. Input to power switch B.

Truth Table Table 1.

SEL	EN	Switch A	Switch B	V <sub>OUT</sub>	Status
LOW	HIGH	ON	OFF	V <sub>IN</sub> A	V <sub>IN</sub> A Selected
HIGH	HIGH	OFF	ON	V <sub>IN</sub> B	V <sub>IN</sub> B Selected
Х	LOW	OFF	OFF	Floating for FPF1320 GND for FPF1321	Both Switches are OFF

# **Absolute Maximum Ratings**

Stresses exceeding the Absolute Maximum Ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Min.	Max.	Unit		
V <sub>IN</sub>	V <sub>IN</sub> A, V <sub>IN</sub> B, V <sub>SEL</sub> , V <sub>EN</sub> , V <sub>OUT</sub>	to GND	-0.3	6	V	
I <sub>SW</sub>	Maximum Continuous Switch	h Current per Channel		1.5	Α	
$P_D$	Total Power Dissipation at 1	「 <sub>A</sub> =25°C		1.2	W	
T <sub>STG</sub>	Operating and Storage June	ction Temperature	-65	150	°C	
	Thermal Resistance, Junction-to-Ambient			85 <sup>(1)</sup>	°C/M	
$\Theta_{JA}$	(1 in. <sup>2</sup> Pad of 2-oz. Copper)			110 <sup>(2)</sup>	°C/W	
		Human Body Model, JESD22-A114	6.0			
	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	1.5			
ESD		Air Discharge (V <sub>IN</sub> A, V <sub>IN</sub> B to GND), IEC61000-4-2 System Level	15.0		kV	
		Contact Discharge (V <sub>IN</sub> A, V <sub>IN</sub> B to GND), IEC61000-4-2 System Level	8.0			

#### Notes:

- 1. Measured using 2S2P JEDEC std. PCB.
- 2. Measured using 2S2P JEDEC PCB cold-plate method.

# **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameters	Min.	Max.	Unit
$V_{IN}$	V <sub>IN</sub> Input Voltage on V <sub>IN</sub> A, V <sub>IN</sub> B		5.5	V
T <sub>A</sub>			85	°C

# **Electrical Characteristics**

 $V_{IN}A=V_{IN}B=1.5$  to 5.5 V,  $T_A=-40$  to 85°C unless otherwise noted. Typical values are at  $V_{IN}A=V_{IN}B=3.3$  V and  $T_A=25$ °C.

Symbol	Parameters	Condition	Min.	Тур.	Max.	Unit	
Basic Operation	on		•	•			
V <sub>IN</sub> A, V <sub>IN</sub> B	Input Voltage		1.5		5.5	V	
I <sub>SD</sub>	Shutdown Current	SEL=HIGH or LOW, EN=GND, V <sub>OUT</sub> =GND, V <sub>IN</sub> A=V <sub>IN</sub> B=5.5 V			5	μA	
IQ	Quiescent Current	I <sub>OUT</sub> =0mA, SEL=HIGH or LOW, EN=HIGH, V <sub>IN</sub> A=V <sub>IN</sub> B=5.5 V		12	22	μΑ	
		V <sub>IN</sub> A=V <sub>IN</sub> B=5.5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		42	60		
В	On-Resistance	V <sub>IN</sub> A=V <sub>IN</sub> B=3.3 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		50		<b></b> 0	
R <sub>ON</sub>	On-Resistance	V <sub>IN</sub> A=V <sub>IN</sub> B=1.8 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C to 85°C		80		— mΩ	
		V <sub>IN</sub> A=V <sub>IN</sub> B=1.5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C			170	,	
$V_{IH}$	SEL, EN Input Logic High Voltage	V <sub>IN</sub> A, V <sub>IN</sub> B=1.5 V – 5.5 V	1.15			V	
V	SEL, EN Input Logic Low Voltage	V <sub>IN</sub> A, V <sub>IN</sub> B=1.8 V – 5.5 V			0.65	٧	
$V_{IL}$	SEL, EN Input Logic Low Voltage	V <sub>IN</sub> A, V <sub>IN</sub> B=1.5 V – 1.8 V			0.60		
V <sub>DROOP_OUT</sub>	Output Voltage Droop while Channel Switching from Higher Input Voltage Lower Input Voltage <sup>(3)</sup>	$V_{IN}A=3.3~V,~V_{IN}B=5~V,~Switching~from V_{IN}A \rightarrow V_{IN}B,~R_L=150~\Omega,~C_{OUT}=1~\mu F$			100	mV	
I <sub>SEL</sub> /I <sub>EN</sub>	Input Leakage at SEL and EN Pin				1.2	μΑ	
R <sub>SEL_PD</sub> /R <sub>EN_PD</sub>	Pull-Down Resistance at SEL or EN Pin			7		МΩ	
$R_{PD}$	Output Pull-Down Resistance	SEL=HIGH or LOW, EN=GND, I <sub>FORCE</sub> =20 mA, T <sub>A</sub> =25°C, FPF1321		65		Ω	
True Reverse	Current Blocking						
V <sub>T_RCB</sub>	RCB Protection Trip Point	V <sub>OUT</sub> - V <sub>IN</sub> A or V <sub>IN</sub> B		45	1	mV	
V <sub>R_RCB</sub>	RCB Protection Release Trip Point	V <sub>IN</sub> A or V <sub>IN</sub> B -V <sub>OUT</sub>		25		mV	
I <sub>RCB</sub>	V <sub>IN</sub> A or V <sub>IN</sub> B Current During RCB	V <sub>OUT</sub> =5.5 V, V <sub>IN</sub> A or V <sub>IN</sub> B=Short to GND		9	15	μΑ	
t <sub>RCB_ON</sub>	RCB Response Time when Device is ON <sup>(3)</sup>	V <sub>IN</sub> A or V <sub>IN</sub> B=5 V, V <sub>OUT</sub> V <sub>INA,B</sub> =100 mV		5		μs	

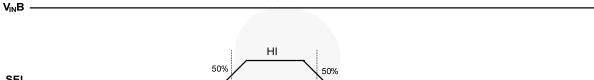
# **Electrical Characteristics** (Continued)

 $V_{IN}A=V_{IN}B=1.5$  to 5.5 V,  $T_A=-40$  to 85°C unless otherwise noted. Typical values are at  $V_{IN}A=V_{IN}B=3.3$  V and  $T_A=25$ °C.

Symbol	Parameters	Condition	Min.	Тур.	Max.	Unit
Dynamic Cha	aracteristics	1	l	1	I	
t <sub>DON</sub>	Turn-On Delay <sup>(4)</sup>	V <sub>IN</sub> A or V <sub>IN</sub> B=3.3 V, R <sub>L</sub> =150 Ω,		120		μs
t <sub>R</sub>	V <sub>OUT</sub> Rise Time <sup>(4)</sup>	C <sub>L</sub> =1 μF, T <sub>A</sub> =25°C, SEL: HIGH,		130		μs
t <sub>ON</sub>	Turn-On Time <sup>(6)</sup>	EN: LOW → HIGH		250		μs
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4)</sup>	$V_{IN}A$ or $V_{IN}B=3.3$ V, $R_{I}=150$ $\Omega$ ,		15		μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4)</sup>	C <sub>L</sub> =1 μF, T <sub>A</sub> =25°C, SEL: HIGH,		320		μs
t <sub>OFF</sub>	Turn-Off Time <sup>(7)</sup>	EN: HIGH → LOW		335		μs
t <sub>DOFF</sub>	Turn-Off Delay <sup>(4,5)</sup>	$V_{IN}A$ or $V_{IN}B$ =3.3 V, $R_L$ =150 $\Omega$ ,		6		μs
t <sub>F</sub>	V <sub>OUT</sub> Fall Time <sup>(4,5)</sup>	$C_L=1 \mu F$ , $T_A=25^{\circ}C$ , SEL: HIGH, EN: HIGH $\rightarrow$ LOW,		110		μs
t <sub>OFF</sub>	Turn-Off Time <sup>(5,7)</sup>	Output Discharge Mode, FPF1321		116		μs
t <sub>TRANR</sub>	Transition Time LOW → HIGH <sup>(4)</sup>	$V_{IN}A=3.3 \text{ V}, V_{IN}B=5 \text{ V},$ Switching from $V_{IN}A \rightarrow V_{IN}B$ ,		3		μs
t <sub>SLH</sub>	Switch-Over Rising Delay <sup>(4)</sup>	SEL: LOW $\rightarrow$ HIGH, EN: HIGH, R <sub>L</sub> =150 $\Omega$ , C <sub>L</sub> =1 $\mu$ F, T <sub>A</sub> =25°C	\ \	1		μs
t <sub>TRANF</sub>	Transition Time HIGH → LOW <sup>(4)</sup>	$V_{IN}A=3.3 \text{ V}, V_{IN}B=5 \text{ V},$ Switching from VINB $\rightarrow$ $V_{IN}A$ ,		45		μs
t <sub>SHL</sub>	Switch-Over Falling Delay <sup>(4)</sup>	SEL: HIGH $\rightarrow$ LOW, EN: HIGH, R <sub>L</sub> =150 $\Omega$ , C=1 $\mu$ F, T <sub>A</sub> =25°C		5		μs

- This parameter is guaranteed by design and characterization; not production tested.
- $t_{DON}/t_{DOFF}/t_R/t_F/t_{TRANR}/t_{TRANF}/t_{SLH}/t_{SHL} \ are \ defined \ in \ Figure \ 5.$  FPF1321 output discharge is enabled during off.
- $t_{ON}=t_R+t_{DON}$ .
- $t_{OFF} = t_F + t_{DOFF}$ .

# Timing Diagram V<sub>IN</sub>A \_\_\_\_\_\_



3.3V

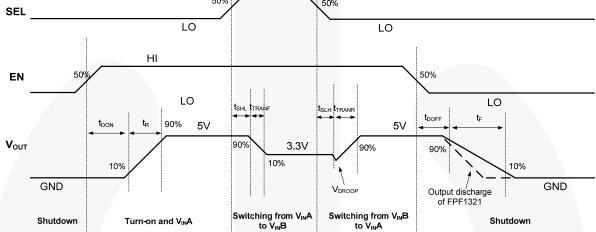


Figure 5. Dynamic Behavior Timing Diagram

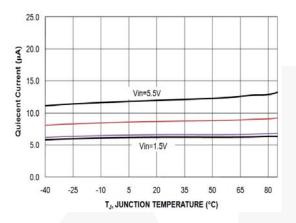


Figure 6. Supply Current vs. Temperature

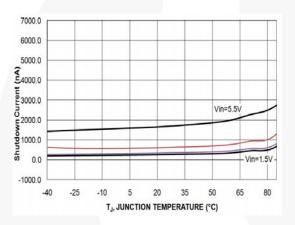


Figure 8. Shutdown Current vs. Temperature

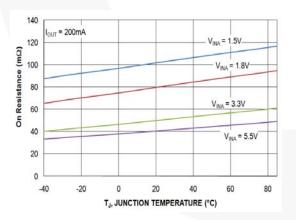


Figure 10. Ron vs. Temperature

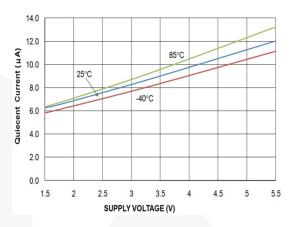


Figure 7. Supply Current vs. Supply Voltage

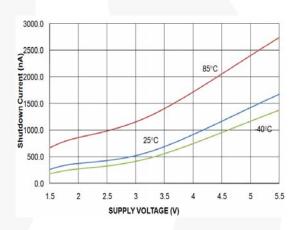


Figure 9. Shutdown Current vs. Supply Voltage

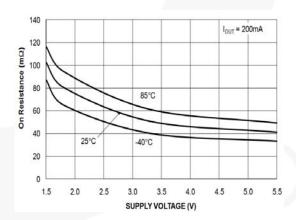


Figure 11. Ron vs. Supply Voltage

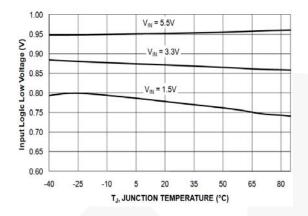


Figure 12. V<sub>IL</sub> vs. Temperature

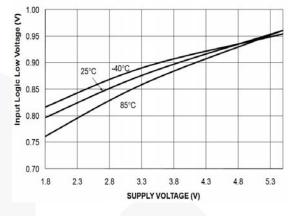


Figure 13. VIL vs. Supply Voltage

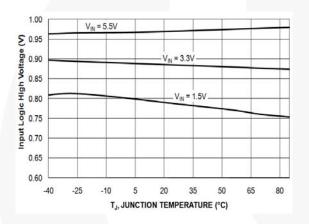


Figure 14. V<sub>IH</sub> vs. Temperature

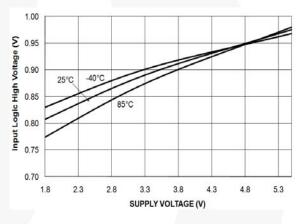


Figure 15. V<sub>IH</sub> vs. Supply Voltage

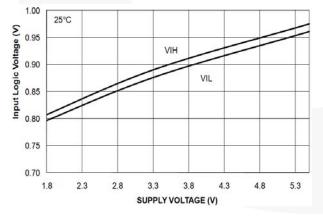


Figure 16.  $V_{IH}$  /  $V_{IL}$  vs. Supply Voltage

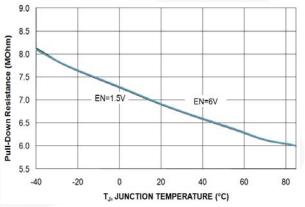


Figure 17. R<sub>SEL\_PD</sub> and R<sub>EN\_PD</sub> vs. Temperature

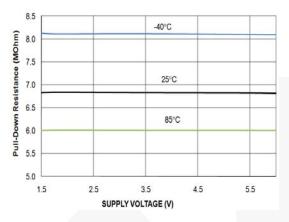


Figure 18. R<sub>SEL\_PD</sub> and R<sub>EN\_PD</sub> vs. Supply Voltage

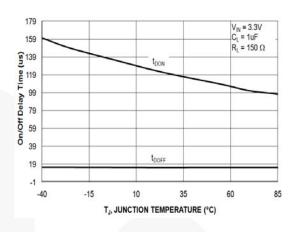


Figure 19. t<sub>DON</sub> and t<sub>DOFF</sub> vs. Temperature

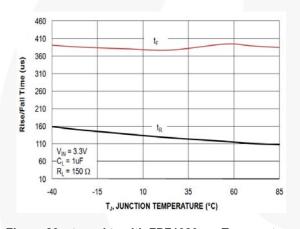


Figure 20.  $\,t_R$  and  $\,t_F$  with FPF1320 vs. Temperature

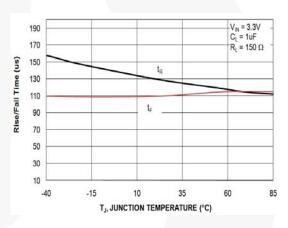


Figure 21. t<sub>R</sub> and t<sub>F</sub> with FPF1321 vs. Temperature

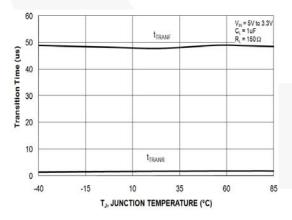


Figure 22. Transition Time vs. Temperature

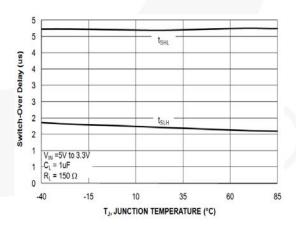
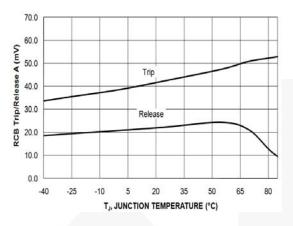


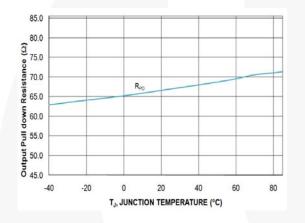
Figure 23. Switch Over Time vs. Temperature



12.0 11.0 10.0 9.0 (MA) 8.0 IRCB 7.0 6.0 5.0 4.0 20 35 50 65 80 -40 -25 -10 T,, JUNCTION TEMPERATURE (°C)

Figure 24. TRCB Trip and Release vs. Temperature

Figure 25. I<sub>RCB</sub> vs. Temperature



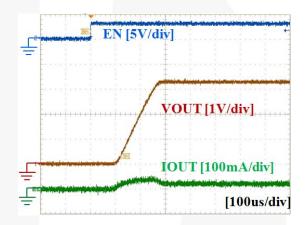
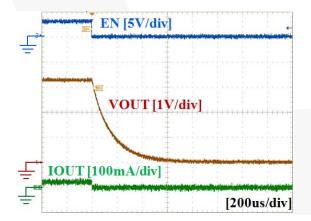


Figure 26. R<sub>PD</sub> with FPF1321 vs. Temperature

Figure 27. Turn-On Response (V<sub>IN</sub>A=3.3 V, C<sub>IN</sub>=1  $\mu$ F, C<sub>OUT</sub>=1  $\mu$ F, R<sub>L</sub>=150  $\Omega$ , SEL=LOW)



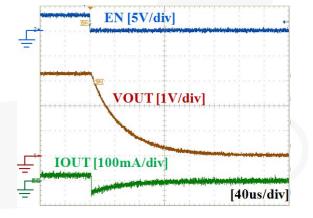
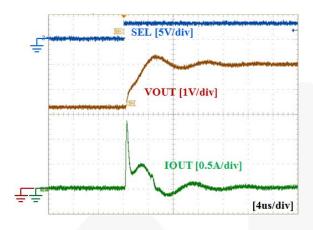
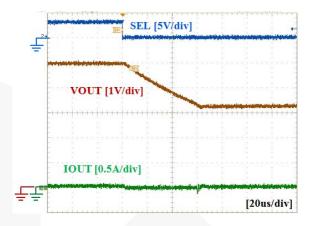


Figure 28. Turn-Off Response with FPF1320 ( $V_{IN}A=3.3~V,~C_{IN}=1~\mu F,~C_{OUT}=1~\mu F,~R_L=150~\Omega,~SEL=LOW$ )

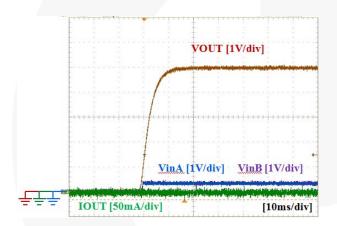
Figure 29. Turn-Off Response with FPF1321 ( $V_{IN}A=3.3~V,~C_{IN}=1~\mu F,~C_{OUT}=1~\mu F,~R_L=150~\Omega,~SEL=LOW$ )





( $V_{IN}A=3.3 \text{ V}, V_{IN}B=5 \text{ V}, C_{IN}=1 \mu\text{F}, C_{OUT}=1 \mu\text{F},$  $R_L=150 \Omega$ )

Figure 30. Power Source Transition from 3.3 V to 5 V Figure 31. Power Source Transition from 5 V to 3.3 V ( $V_{IN}A=3.3 V$ ,  $V_{IN}B=5 V$ ,  $C_{IN}=1 \mu F$ ,  $C_{OUT}=1 \mu F$ ,  $R_L=150 \Omega$ )



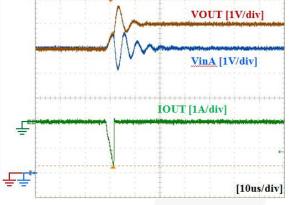


Figure 32. TRCB During Off (V<sub>IN</sub>A=V<sub>IN</sub>B=Floating,  $V_{OUT}$ =5V,  $C_{IN}$ =1  $\mu$ F,  $C_{OUT}$ =1  $\mu$ F, EN=LOW, No R<sub>L</sub>)

Figure 33. TRCB During On (V<sub>IN</sub>A=5 V, V<sub>OUT</sub>=6 V, C<sub>IN</sub>=1  $\mu$ F, C<sub>OUT</sub>=1  $\mu$ F, EN=HIGH, No R<sub>L</sub>)

## **Operation and Application Description**

The FPF1320 and FPF1321 are dual-input single-output power multiplexer switches with controlled turn-on and seamless power source transition. The core is a 50 m $\Omega$  P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.5 V to 5.5 V per channel. The EN and SEL pins are active-HIGH, GPIO/CMOS-compatible input. They control the state of the switch and input power source selection, respectively. TRCB functionality blocks unwanted reverse current during both ON and OFF states when higher  $V_{\text{OUT}}$  than  $V_{\text{IN}}$ A or  $V_{\text{IN}}$ B is applied. FPF1321 has a 65  $\Omega$  output discharge path during off.

#### **Input Capacitor**

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor; a capacitor must be placed between the  $V_{IN}A$  or  $V_{IN}B$  pins to the GND pin. At least 1  $\mu F$  ceramic capacitor,  $C_{IN}$ , placed close to the pins, is usually sufficient. Higher-value  $C_{IN}$  can be used to reduce more the voltage drop.

#### **Inrush Current**

Inrush current occurs when the device is turned on. Inrush current is dependent on output capacitance and slew rate control capability, as expressed by:

$$I_{\mathit{INRUSH}} = C_{\mathit{OUT}} \times \frac{V_{\mathit{IN}} - V_{\mathit{INITIAL}}}{t_{\mathit{R}}} + I_{\mathit{LOAD}} \tag{1}$$

where:

C<sub>OUT</sub>: Output capacitance;

t<sub>R</sub>: Slew rate or rise time at V<sub>OUT</sub>;

V<sub>IN</sub>: Input voltage, V<sub>IN</sub>A or V<sub>IN</sub>B;

VINITIAL: Initial voltage at COUT, usually GND; and

I<sub>LOAD</sub>: Load current.

Higher inrush current causes higher input voltage drop, depending on the distributed input resistance and input capacitance. High inrush current can cause problems.

FPF1320/1 has a 130  $\mu s$  of slew rate capability under 3.3  $V_{IN}$  at 1  $\mu F$  of  $C_{OUT}$  and 150  $\Omega$  of  $R_L$  so inrush current and input voltage drop can be minimized.

#### **Power Source Selection**

Input power source selection can be controlled by the SEL pin. When SEL is LOW, output is powered from  $V_{\text{IN}}A$  while SEL is HIGH,  $V_{\text{IN}}B$  is powering output. The SEL signal is ignored during device OFF.

#### **Output Voltage Drop during Transition**

Output voltage drop usually occurs during input power source transition period from low voltage to high voltage. The drop is highly dependent on output capacitance and load current.

FPF1320/1 adopts an advanced break-before-make control, which can result in minimized output voltage drop during the transition time.

#### **Output Capacitor**

Capacitor  $C_{\text{OUT}}$  of at least 1  $\mu\text{F}$  is highly recommended between the  $V_{\text{OUT}}$  and GND pins to achieve minimized output voltage drop during input power source transition. This capacitor also prevents parasitic board inductance.

#### **True Reverse-Current Blocking**

The true reverse-current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

#### **Board Layout**

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance on normal and short-circuit operation. Wide traces or large copper planes for power pins ( $V_{\text{IN}}A$ ,  $V_{\text{IN}}B$ ,  $V_{\text{OUT}}$  and GND) minimize the parasitic electrical effects and the thermal impedance.

# **Physical Dimensions**

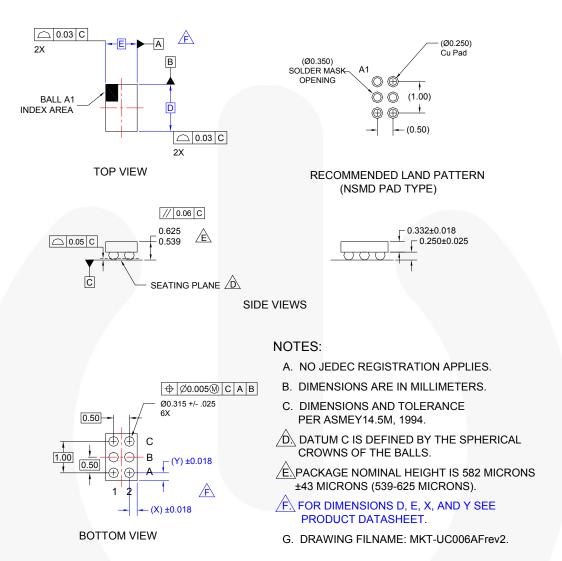


Figure 34. 6-Ball, 1.0 x 1.5 mm, Wafer-Level Chip-Scale Package (WLCSP)

# **Product-Specific Dimensions**

Product	D	E	X	Y
FPF1320UCX	1460 µm ±30 µm	960 μm ±30 μm	230 μm	230 μm
FPF1321UCX	1460 µm ±30 µm	960 μm ±30 μm	230 μm	230 μm
FPF1321BUCX	1460 µm ±30 µm	960 μm ±30 μm	230 μm	230 μm

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